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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	66MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (2), 10/100Mbps (2)
SATA	-
USB	USB 2.0 (1)
Voltage - I/O	3.3V
Operating Temperature	-40°C ~ 100°C (TA)
Security Features	-
Package / Case	357-BBGA
Supplier Device Package	357-PBGA (25x25)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc880cvr66

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



1 Overview

The MPC885/MPC880 is a versatile single-chip integrated microprocessor and peripheral combination that can be used in a variety of controller applications and communications and networking systems. The MPC885/MPC880 provides enhanced ATM functionality, an additional fast Ethernet controller, a USB, and an encryption block.

Table 1 shows the functionality supported by MPC885/MPC880.

Part	Cache (Kbytes)		Ethernet		500	SMC	USB	ATM Support	Security
Tart	I Cache	D Cache	10BaseT	10/100	300	51110	000		Engine
MPC885	8	8	Up to 3	2	3	2	1	Serial ATM and UTOPIA interface	Yes
MPC880	8	8	Up to 2	2	2	2	1	Serial ATM and UTOPIA interface	No

Table 1. MPC885 Family

2 Features

The MPC885/MPC880 is comprised of three modules that each use the 32-bit internal bus: a MPC8xx core, a system integration unit (SIU), and a communications processor module (CPM).

The following list summarizes the key MPC885/MPC880 features:

- Embedded MPC8xx core up to 133 MHz
- Maximum frequency operation of the external bus is 80 MHz (in 1:1 mode)
 - The 133-MHz core frequency supports 2:1 mode only.
 - The 66-/80-MHz core frequencies support both the 1:1 and 2:1 modes.
- Single-issue, 32-bit core (compatible with the Power Architecture definition) with thirty-two 32-bit general-purpose registers (GPRs)
 - The core performs branch prediction with conditional prefetch and without conditional execution.
 - 8-Kbyte data cache and 8-Kbyte instruction cache (see Table 1)
 - Instruction cache is two-way, set-associative with 256 sets in 2 blocks
 - Data cache is two-way, set-associative with 256 sets
 - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks.
 - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
 - MMUs with 32-entry TLB, fully associative instruction and data TLBs
 - MMUs support multiple page sizes of 4, 16, and 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and 16 protection groups
 - Advanced on-chip emulation debug mode





- Provides enhanced ATM functionality found on the MPC862 and MPC866 families and includes the following:
 - Improved operation, administration and maintenance (OAM) support
 - OAM performance monitoring (PM) support
 - Multiple APC priority levels available to support a range of traffic pace requirements
 - Port-to-port switching capability without the need for RAM-based microcode
 - Simultaneous MII (100BaseT) and UTOPIA (half- or full -duplex) capability
 - Optional statistical cell counters per PHY
 - UTOPIA L2-compliant interface with added FIFO buffering to reduce the total cell transmission time and multi-PHY support. (The earlier UTOPIA L1 specification is also supported.)
 - Parameter RAM for both SPI and I²C can be relocated without RAM-based microcode
 - Supports full-duplex UTOPIA master (ATM side) and slave (PHY side) operations using a split bus
 - AAL2/VBR functionality is ROM-resident
 - Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
 - Thirty-two address lines
 - Memory controller (eight banks)
 - Contains complete dynamic RAM (DRAM) controller
 - Each bank can be a chip select or \overline{RAS} to support a DRAM bank
 - Up to 30 wait states programmable per memory bank
 - Glueless interface to DRAM, SIMMS, SRAM, EPROMs, Flash EPROMs, and other memory devices
 - DRAM controller programmable to support most size and speed memory interfaces
 - Four \overline{CAS} lines, four \overline{WE} lines, and one \overline{OE} line
 - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
 - Variable block sizes (32 Kbytes–256 Mbytes)
 - Selectable write protection
 - On-chip bus arbitration logic
 - General-purpose timers
 - Four 16-bit timers or two 32-bit timers
 - Gate mode can enable/disable counting.
 - Interrupt can be masked on reference match and event capture
 - Two fast Ethernet controllers (FEC)—Two 10/100 Mbps Ethernet/IEEE Std. 802.3™ CDMA/CS that interface through MII and/or RMII interfaces
 - System integration unit (SIU)
 - Bus monitor
 - Software watchdog

Maximum Tolerated Ratings



3 Maximum Tolerated Ratings

This section provides the maximum tolerated voltage and temperature ranges for the MPC885/MPC880. Table 2 displays the maximum tolerated ratings, and Table 3 displays the operating temperatures.

Rating	Symbol	Value	Unit
Supply voltage ¹	V _{DDH}	-0.3 to 4.0	V
	V _{DDL}	-0.3 to 2.0	V
	VDDSYN	-0.3 to 2.0	V
	Difference between V_{DDL} and V_{DDSYN}	<100	mV
Input voltage ²	V _{in}	GND – 0.3 to V _{DDH}	V
Storage temperature range	T _{stg}	-55 to +150	°C

Table 2. Maximum Tolerated Ratings

 $^{1}\,$ The power supply of the device must start its ramp from 0.0 V.

² Functional operating conditions are provided with the DC electrical specifications in Table 6. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device. See Section 8, "Power Supply and Power Sequencing." Caution: All inputs that tolerate 5 V cannot be more than 2.5 V greater than V_{DDH}. This restriction applies to power up and normal operation (that is, if the MPC885/MPC880 is unpowered, a voltage greater than 2.5 V must not be applied to its inputs).

Figure 3 shows the undershoot and overshoot voltages at the interfaces of the MPC885/MPC880.



1. t_{interface} refers to the clock period associated with the bus clock interface.

Figure 3. Undershoot/Overshoot Voltage for $\rm V_{DDH}$ and $\rm V_{DDL}$





5 **Power Dissipation**

Table 5 provides information on power dissipation. The modes are 1:1, where CPU and bus speeds are equal, and 2:1, where CPU frequency is twice bus speed.

Die Revision	Bus Mode	CPU Frequency	Typical ¹	Maximum ²	Unit
0	1:1	66 MHz	310	390	mW
		80 MHz	350	430	mW
	2:1	133 MHz	430	495	mW

Table 5. Power Dissipation (PD)

¹ Typical power dissipation at $V_{DDL} = V_{DDSYN} = 1.8$ V, and V_{DDH} is at 3.3 V.

 2 Maximum power dissipation at V_DDL = V_DDSYN = 1.9 V, and V_DDH is at 3.5 V.

NOTE

The values in Table 5 represent V_{DDL} -based power dissipation and do not include I/O power dissipation over V_{DDH} . I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

The V_{DDSYN} power dissipation is negligible.

6 DC Characteristics

Table 6 provides the DC electrical characteristics for the MPC885/MPC880.

Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Unit
Operating voltage	V _{DDL} (core)	1.7	1.9	V
	V _{DDH} (I/O)	3.135	3.465	V
	V _{DDSYN} ¹	1.7	1.9	V
	Difference between V _{DDL} and V _{DDSYN}	—	100	mV
Input high voltage (all inputs except EXTAL and EXTCLK) ²	V _{IH}	2.0	3.465	V
Input low voltage ³	V _{IL}	GND	0.8	V
EXTAL, EXTCLK input high voltage	V _{IHC}	0.7*(V _{DDH})	V _{DDH}	V
Input leakage current, Vin = 5.5 V (except TMS, TRST, DSCK and DSDI pins) for 5-V tolerant pins 2	l _{in}	—	100	μA
Input leakage current, $V_{in} = V_{DDH}$ (except TMS, TRST, DSCK, and DSDI)	I _{In}	—	10	μA
Input leakage current, $V_{in} = 0 V$ (except TMS, TRST, DSCK and DSDI pins)	l _{in}	_	10	μA
Input capacitance ⁴	C _{in}	—	20	pF



7.6 References

Semiconductor Equipment and Materials International(415) 964-5111 805 East Middlefield Rd Mountain View, CA 94043

MIL-SPEC and EIA/JESD (JEDEC) specifications800-854-7179 or (Available from Global Engineering Documents)303-397-7956

JEDEC Specifications http://www.jedec.org

- 1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
- 2. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

8 Power Supply and Power Sequencing

This section provides design considerations for the MPC885/MPC880 power supply. The MPC885/MPC880 has a core voltage (V_{DDL}) and PLL voltage (V_{DDSYN}), which both operate at a lower voltage than the I/O voltage V_{DDH} . The I/O section of the MPC885/MPC880 is supplied with 3.3 V across V_{DDH} and V_{SS} (GND).

The signals PA[0:15], PB[14:31], PC[4:15], PD[3:15], TDI, TDO, TCK, TRST_B, TMS, MII_TXEN, and MII_MDIO are 5 V tolerant. All inputs cannot be more than 2.5 V greater than V_{DDH}. In addition, 5-V tolerant pins cannot exceed 5.5 V and remaining input pins cannot exceed 3.465 V. This restriction applies to power up/down and normal operation.

One consequence of multiple power supplies is that when power is initially applied the voltage rails ramp up at different rates. The rates depend on the nature of the power supply, the type of load on each power supply, and the manner in which different voltages are derived. The following restrictions apply:

- V_{DDL} must not exceed V_{DDH} during power up and power down.
- V_{DDL} must not exceed 1.9 V, and V_{DDH} must not exceed 3.465 V.

These cautions are necessary for the long-term reliability of the part. If they are violated, the electrostatic discharge (ESD) protection diodes are forward-biased, and excessive current can flow through these diodes. If the system power supply design does not control the voltage sequencing, the circuit shown Figure 5 can be added to meet these requirements. The MUR420 Schottky diodes control the maximum potential difference between the external bus and core power supplies on power up, and the 1N5820 diodes regulate the maximum potential difference on power down.





Figure 5. Example Voltage Sequencing Circuit

9 Layout Practices

Each V_{DD} pin on the MPC885/MPC880 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{DD} power supply should be bypassed to ground using at least four 0.1 µF by-pass capacitors located as close as possible to the four sides of the package. Each board designed should be characterized and additional appropriate decoupling capacitors should be used if required. The capacitor leads and associated printed-circuit traces connecting to chip V_{DD} and GND should be kept to less than half an inch per capacitor lead. At a minimum, a four-layer board employing two inner layers as V_{DD} and GND planes should be used.

All output pins on the MPC885/MPC880 have fast rise and fall times. Printed-circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{DD} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins. For more information, please refer to the *MPC885 PowerQUICCTM Family Reference Manual*, Section 14.4.3, "Clock Synthesizer Power (V_{DDSYN} , V_{SSSYN} , V_{SSSYN1})."

10 Bus Signal Timing

The maximum bus speed supported by the MPC885/MPC880 is 80 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC885/MPC880 used at 133 MHz must be configured for a 66 MHz bus). Table 7 shows the frequency ranges for standard part frequencies in 1:1 bus mode, and Table 8 shows the frequency ranges for standard part frequencies in 2:1 bus mode.



Num	Chavastavistis	33	33 MHz		40 MHz		MHz	80 MHz		l lm it
NUM			Мах	Min	Мах	Min	Мах	Min	Мах	Unit
B32	CLKOUT falling edge to $\overline{\text{BS}}$ valid, as requested by control bit BST4 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 6.00$)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to $\overline{\text{BS}}$ valid, as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B32b	CLKOUT rising edge to $\overline{\text{BS}}$ valid, as requested by control bit BST2 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 8.00$)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to $\overline{\text{BS}}$ valid, as requested by control bit BST3 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B32d	CLKOUT falling edge to $\overline{\text{BS}}$ valid, as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 1 (MAX = 0.375 × B1 + 6.60)	13.30	18.00	11.30	16.00	7.60	12.30	4.49	11.30	ns
B33	CLKOUT falling edge to $\overline{\text{GPL}}$ valid, as requested by control bit GxT4 in the corresponding word in the UPM (MAX = 0.00 × B1 + 6.00)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B33a	CLKOUT rising edge to $\overline{\text{GPL}}$ valid, as requested by control bit GxT3 in the corresponding word in the UPM (MAX = $0.25 \times B1 + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B34	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by control bit CST4 in the corresponding word in the UPM (MIN = $0.25 \times B1 - 2.00$)	5.60	_	4.30		1.80	_	1.13		ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by control bit CST1 in the corresponding word in the UPM (MIN = $0.50 \times B1 - 2.00$)	13.20	_	10.50		5.60	_	4.25		ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid, as requested by CST2 in the corresponding word in UPM (MIN = $0.75 \times B1 - 2.00$)	20.70	_	16.70		9.40	_	6.80	_	ns
B35	A(0:31), BADDR(28:30) to $\overline{\text{CS}}$ valid, as requested by control bit BST4 in the corresponding word in the UPM (MIN = $0.25 \times \text{B1} - 2.00$)	5.60	_	4.30		1.80	_	1.13		ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to \overline{BS} valid, as requested by BST1 in the corresponding word in the UPM (MIN = $0.50 \times B1 - 2.00$)	13.20		10.50		5.60		4.25		ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to \overline{BS} valid, as requested by control bit BST2 in the corresponding word in the UPM (MIN = 0.75 × B1 - 2.00)	20.70		16.70	_	9.40	_	7.40		ns

Table 9. Bus Operation Timings (continued)















Figure 16. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)



Figure 17 through Figure 19 provide the timing for the external bus write controlled by various GPCM factors.



Figure 17. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 0)



Table 12 shows the PCMCIA port timing for the MPC885/MPC880.

Num	Characteristic	33 MHz		40 MHz		66 MHz		80 MHz		Unit
		Min	Мах	Min	Мах	Min	Мах	Min	Max	Unit
P57	CLKOUT to OPx valid (MAX = $0.00 \times B1 + 19.00$)	—	19.00	—	19.00	—	19.00	-	19.00	ns
P58	HRESET negated to OPx drive ¹ (MIN = $0.75 \times B1 + 3.00$)	25.70	—	21.70	-	14.40	—	12.40	—	ns
P59	IP_Xx valid to CLKOUT rising edge (MIN = $0.00 \times B1 + 5.00$)	5.00	—	5.00		5.00	—	5.00	—	ns
P60	CLKOUT rising edge to IP_Xx invalid (MIN = $0.00 \times B1 + 1.00$)	1.00	—	1.00	_	1.00	—	1.00	—	ns

Table 12. PCMCIA Port Timing

¹ OP2 and OP3 only.

Figure 31 provides the PCMCIA output port timing for the MPC885/MPC880.



Figure 31. PCMCIA Output Port Timing

Figure 32 provides the PCMCIA input port timing for the MPC885/MPC880.



Figure 32. PCMCIA Input Port Timing



IEEE 1149.1 Electrical Specifications





CPM Electrical Characteristics

12 CPM Electrical Characteristics

This section provides the AC and DC electrical specifications for the communications processor module (CPM) of the MPC885/MPC880.

Table 16. PIP/PIO Timing

12.1 PIP/PIO AC Electrical Specifications

Table 16 provides the PIP/PIO AC timings as shown in Figure 42 through Figure 46.

All Frequencies Num Characteristic Unit Min Max 21 Data-in setup time to STBI low 0 ____ ns 22 Data-In hold time to STBI high 0 clk 23 STBI pulse width 1.5 clk 24 STBO pulse width 1 clk – 5 ns ns 25 Data-out setup time to STBO low 2 clk Data-out hold time from STBO high 5 26 clk STBI low to STBO low (Rx interlock) 27 4.5 clk 28 STBI low to STBO high (Tx interlock) 2 clk ____ 29 Data-in setup time to clock high 15 ns 30 Data-in hold time from clock high 7.5 ns Clock low to data-out valid (CPU writes data, control, or direction) 31 25 ns



Figure 42. PIP Rx (Interlock Mode) Timing Diagram





Figure 51. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA

12.4 Baud Rate Generator AC Electrical Specifications

Table 19 provides the baud rate generator timings as shown in Figure 52.

Table 19	. Baud	Rate	Generator	Timing
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Num	Characteristic	All Freq	Unit	
			Max	onit
50	BRGO rise and fall time	—	10	ns
51	BRGO duty cycle	40	60	%
52	BRGO cycle	40	—	ns



Figure 52. Baud Rate Generator Timing Diagram



CPM Electrical Characteristics

Num	Characteristic	All Freq	Unit	
			Мах	Onit
134	TENA inactive delay (from TCLK1 rising edge)	10	50	ns
138	CLKO1 low to SDACK asserted ²	—	20	ns
139	CLKO1 low to SDACK negated ²	—	20	ns

Table 24. Ethernet Timing (continued)

¹ The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater than or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.





Figure 63. Ethernet Receive Timing Diagram



CPM Electrical Characteristics



Figure 65. SMC Transparent Timing Diagram

12.10 SPI Master AC Electrical Specifications

Table 26 provides the SPI master timings as shown in Figure 66 and Figure 67.

Table 26. SPI Master	r Timing
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Num	Characteristic		All Frequencies		
Nulli	Cildiacteristic	Min	Мах	Onit	
160	MASTER cycle time	4	1024	t _{cyc}	
161	MASTER clock (SCK) high or low time	2	512	t _{cyc}	
162	MASTER data setup time (inputs)	15	—	ns	
163	Master data hold time (inputs)	0	—	ns	
164	Master data valid (after SCK edge)	—	10	ns	
165	Master data hold time (outputs)	0	_	ns	
166	Rise time output	—	15	ns	
167	Fall time output	—	15	ns	



14 USB Electrical Characteristics

This section provides the AC timings for the USB interface.

14.1 USB Interface AC Timing Specifications

The USB Port uses the transmit clock on SCC1. Table 33 lists the USB interface timings.

Table 33. USB Interface AC Timing Specifications

Name	Characteristic	All Freq	Unit	
		Min	Max	
US1	USBCLK frequency of operation ¹ Low speed Full speed	6 4	MHz MHz	
US4	USBCLK duty cycle (measured at 1.5 V)	45	55	%

¹ USBCLK accuracy should be ±500 ppm or better. USBCLK may be stopped to conserve power.

15 FEC Electrical Characteristics

This section provides the AC electrical specifications for the fast Ethernet controller (FEC). Note that the timing specifications for the MII signals are independent of system clock frequency (part speed designation). Also, MII signals use TTL signal levels compatible with devices operating at either 5.0 or 3.3 V.

15.1 MII and Reduced MII Receive Signal Timing

The receiver functions correctly up to a MII_RX_CLK maximum frequency of 25 MHz + 1%. The reduced MII (RMII) receiver functions correctly up to a RMII_REFCLK maximum frequency of 50 MHz + 1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_RX_CLK frequency – 1%.

Table 34 provides information on the MII and RMII receive signal timing.

Num	Characteristic	Min	Max	Unit
M1	MII_RXD[3:0], MII_RX_DV, MII_RX_ERR to MII_RX_CLK setup	5	_	ns
M2	MII_RX_CLK to MII_RXD[3:0], MII_RX_DV, MII_RX_ER hold	5	_	ns
M3	MII_RX_CLK pulse width high	35%	65%	MII_RX_CLK period
M4	MII_RX_CLK pulse width low	35%	65%	MII_RX_CLK period
M1_RMII	RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR to RMII_REFCLK setup	4	_	ns
M2_RMII	RMII_REFCLK to RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR hold	2		ns

Table 34. MII Receive Signal Timing



FEC Electrical Characteristics

Figure 73 shows MII receive signal timing.



Figure 73. MII Receive Signal Timing Diagram

15.2 **MII and Reduced MII Transmit Signal Timing**

The transmitter functions correctly up to a MII_TX_CLK maximum frequency of 25 MHz + 1%. The RMII transmitter functions correctly up to a RMII_REFCLK maximum frequency of 50 MHz + 1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_TX_CLK frequency - 1%.

Table 35 provides information on the MII and RMII transmit signal timing.

Num	Characteristic	Min	Max	Unit
M5	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER invalid	5	_	ns
M6	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER valid	—	25	ns
M20_RMII	RMII_TXD[1:0], RMII_TX_EN to RMII_REFCLK setup	4		ns
M21_RMII	RMII_TXD[1:0], RMII_TX_EN data hold from RMII_REFCLK rising edge	2	_	ns
M7	MII_TX_CLK and RMII_REFCLK pulse width high	35%	65%	MII_TX_CLK or RMII_REFCLK period
M8	MII_TX_CLK and RMII_REFCLK pulse width low	35%	65%	MII_TX_CLK or RMII_REFCLK period

Table 35. MII Transmit Signal Timing



Figure 74 shows the MII transmit signal timing diagram.



Figure 74. MII Transmit Signal Timing Diagram

15.3 MII Async Inputs Signal Timing (MII_CRS, MII_COL)

Table 36 provides information on the MII async inputs signal timing.

Table 36. MII Async Inputs Signal Timing

Num	Characteristic	Min	Max	Unit
M9	MII_CRS, MII_COL minimum pulse width	1.5	_	MII_TX_CLK period

Figure 75 shows the MII asynchronous inputs signal timing diagram.



15.4 MII Serial Management Channel Timing (MII_MDIO, MII_MDC)

Table 37 provides information on the MII serial management channel signal timing. The FEC functions correctly with a maximum MDC frequency in excess of 2.5 MHz.

Table 37. MII Serial Management Channel	el Timing
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Num	Characteristic	Min	Мах	Unit
M10	MII_MDC falling edge to MII_MDIO output invalid (minimum propagation delay)	0		ns
M11	MII_MDC falling edge to MII_MDIO output valid (max prop delay)		25	ns
M12	MII_MDIO (input) to MII_MDC rising edge setup	10	_	ns
M13	MII_MDIO (input) to MII_MDC rising edge hold	0	_	ns



Mechanical Data and Ordering Information

16.2 Mechanical Dimensions of the PBGA Package

Figure 78 shows the mechanical dimensions of the PBGA package.



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.

2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.

3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.

4. DATUM A, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

Figure 78. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package